



A Product Line of Diodes Incorporated



**FZT751** 

#### **60V PNP HIGH PERFORMANCE TRANSISTOR IN SOT223**

#### Features

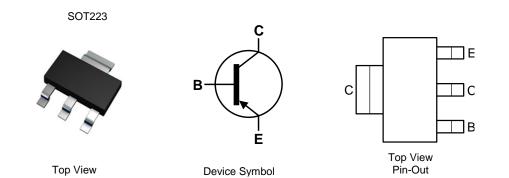
- BV<sub>CEO</sub> > -60V
- I<sub>C</sub> = -3A High Continuous Current
- I<sub>CM</sub> = -6A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -300mV @ -1A</li>
- Complementary NPN Type: FZT651
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

# Applications

- Automotive Lighting
- MOSFET and IGBT Gate Driving



# Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT751TA	AEC-Q101	FZT751	7	12	1,000
FZT751TC	AEC-Q101	FZT751	13	12	4,000

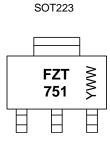
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



FZT 751 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)





#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-3	А
Peak Pulse Current	I <sub>CM</sub>	-6	А

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Rewer Dissinction	(Note 5)	D	2	W
Power Dissipation	(Note 6) P <sub>D</sub>		3	W
Thermal Desistance Junction to Ambient	(Note 5)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>θJA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R <sub>0JL</sub>	12.9	°C/W
Operating and Storage Temperature Range	T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C	

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in steady-state.

6. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.

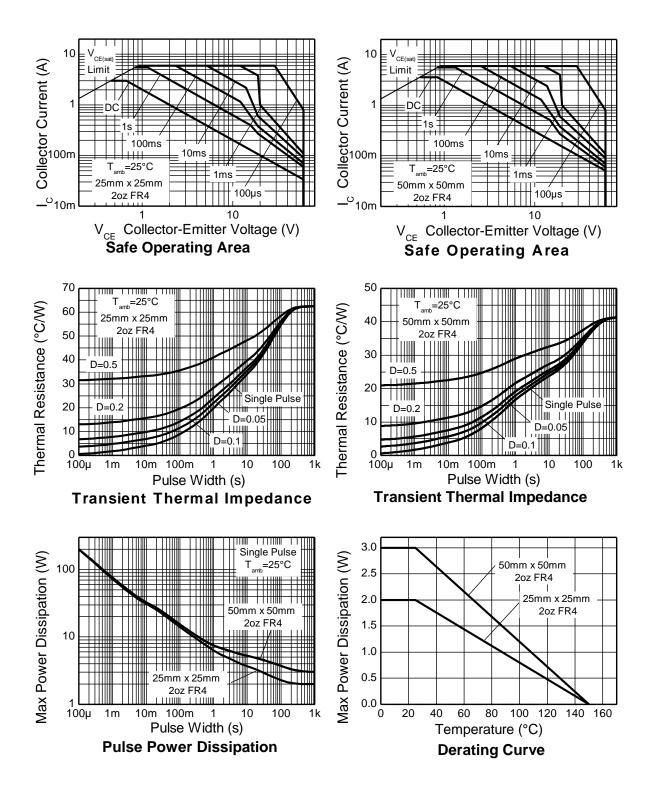
7. Thermal resistance from junction to solder-point (at the end of the collector lead).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





# Thermal Characteristics and Derating Information







# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

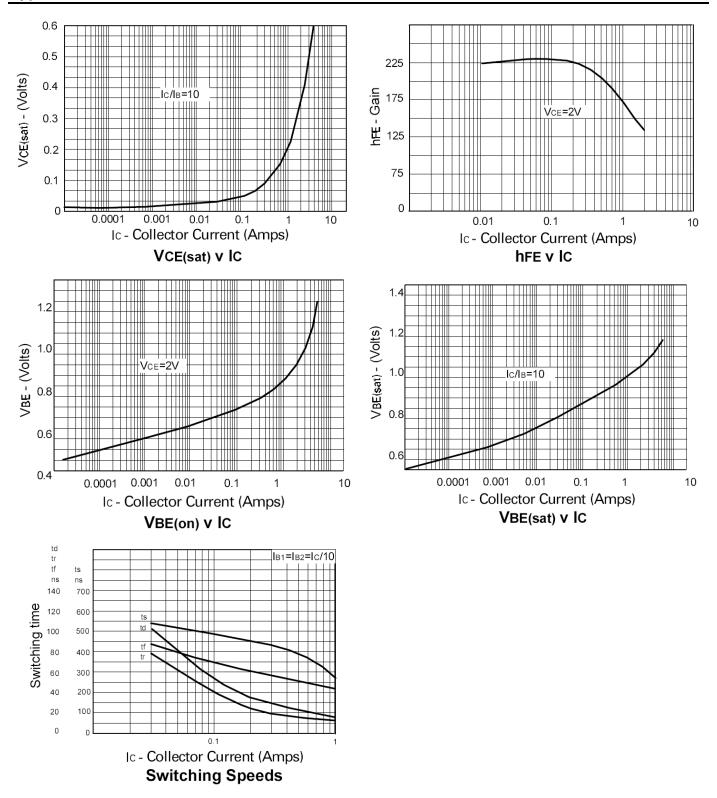
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-80	-	1	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-60	-	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current		-	<1	-100	nA	$V_{CB} = -60V$
	I <sub>CBO</sub>	-	-	-10	μA	$V_{CB} = -60V, T_{amb} = +100^{\circ}C$
Emitter Cut-Off Current	I <sub>EBO</sub>	-	<1	-100	nA	$V_{EB} = -4V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	-0.15	-0.3	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Collector-Emiller Saturation Voltage (Note 9)		-	-0.45	-0.6	v	$I_{C} = -3A, I_{B} = -300mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-0.9	-1.25	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	-0.8	-1.0	V	$I_{C} = -1A, V_{CE} = -2V$
	hFE	70	200	-		$I_{C} = -50 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Coin (Note 0)		100	200	300		I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
DC Current Gain (Note 9)		80	170	-	_	$I_{C} = -1A, V_{CE} = -2V$
		40	150	-		$I_{C} = -2A, V_{CE} = -2V$
Current Gain-Bandwidth Product	f <sub>T</sub>	100	140	-	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -100mA f = 100MHz
Turn-On Time	t <sub>on</sub>	-	40	-	ns	$V_{CC} = -10V, I_{C} = -500mA$
Turn-Off Time	t <sub>off</sub>	-	450	-	ns	$I_{B1} = I_{B2} = -50 \text{mA}$
Output Capacitance	C <sub>obo</sub>	-	_	30	pF	$V_{CB} = -10V, f = 1MHz$

9. Measured under pulsed conditions. Pulse width  $\leq$  300 µs. Duty cycle  $\leq$  2%. Note:





## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

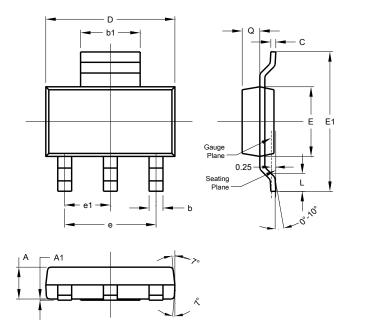






## **Package Outline Dimensions**

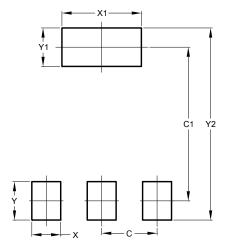
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
ш	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00





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